

DMN3016LDN-13 Datasheet



| | |
|------------------------------|---|
| DiGi Electronics Part Number | DMN3016LDN-13-DG |
| Manufacturer | Diodes Incorporated |
| Manufacturer Product Number | DMN3016LDN-13 |
| Description | MOSFET 2N-CH 9.2A 8VDFN |
| Detailed Description | Mosfet Array 9.2A (Ta) Surface Mount V-DFN3030-8 (Type J) |

<https://www.DiGi-Electronics.com>



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

DMN3016LDN-13

Series:

-

Technology:

MOSFET (Metal Oxide)

FET Feature:

-

Rds On (Max) @ Id, Vgs:

20mOhm @ 11A, 10V

Gate Charge (Qg) (Max) @ Vgs:

11.3nC @ 4.5V

Operating Temperature:

-55°C ~ 150°C (Tj)

Package / Case:

8-PowerVDFN

Base Product Number:

DMN3016

Manufacturer:

Diodes Incorporated

Product Status:

Active

Configuration:

2 N-Channel (Dual)

Current - Continuous Drain (Id) @ 25°C:

9.2A (Ta)

Vgs(th) (Max) @ Id:

2V @ 250µA

Input Capacitance (Ciss) (Max) @ Vds:

1415pF @ 15V

Mounting Type:

Surface Mount

Supplier Device Package:

V-DFN3030-8 (Type J)

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

Product Summary

| Device | $V_{(BR)DSS}$ | $R_{DS(ON) \max}$ | $I_{D \max}$ $T_A = +25^\circ\text{C}$ |
|-----------|---------------|---------------------------------------|---|
| N-Channel | 30V | 20m Ω @ $V_{GS} = 10\text{V}$ | 7.3A |
| | | 24m Ω @ $V_{GS} = 4.5\text{V}$ | 6.7A |

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

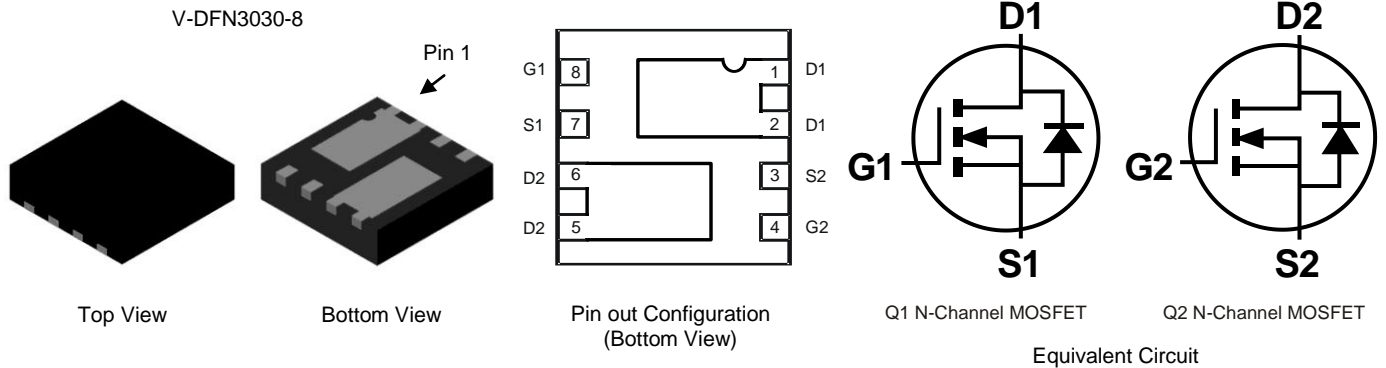
- DC Motor Control
- DC-AC Inverters

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: V-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Weight: 0.02 grams (Approximate)

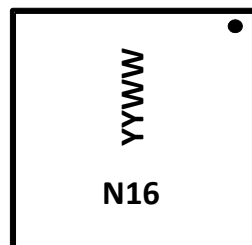


Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|-------------|-------------------|
| DMN3016LDN-7 | V-DFN3030-8 | 3000/Tape & Reel |
| DMN3016LDN-13 | V-DFN3030-8 | 10000/Tape & Reel |

- Notes:
- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



N16 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Digit of Year (ex: 13 for 2013)
 WW = Week Code (01 ~ 53)



DMN3016LDN

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Units |
|---|--------------|--|------------------|------------|-------|
| Drain-Source Voltage | | | V _{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6) V _{GS} = 10V | Steady State | T _A = +25°C T _A = +70°C | I _D | 7.3 5.8 | A |
| | t < 10s | T _A = +25°C T _A = +70°C | I _D | 9.2 7.3 | A |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | I _S | 2.5 | A |
| Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%) | | | I _{DM} | 45 | A |
| Avalanche Current (Note 7) L = 0.1mH | | | I _{AS} | 22 | A |
| Avalanche Energy (Note 7) L = 0.1mH | | | E _{AS} | 24 | mJ |

Thermal Characteristics

| Characteristic | | Symbol | Value | Units |
|--|------------------------|-----------------------------------|-------------|-------|
| Total Power Dissipation (Note 5) | T _A = +25°C | P _D | 1.1 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | R _{θJA} | 119 | °C/W |
| | t < 10s | | 75 | |
| Total Power Dissipation (Note 6) | T _A = +25°C | P _D | 1.6 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | R _{θJA} | 78 | °C/W |
| | t < 10s | | 49 | |
| Thermal Resistance, Junction to Case (Note 6) | | R _{θJC} | 13.5 | |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

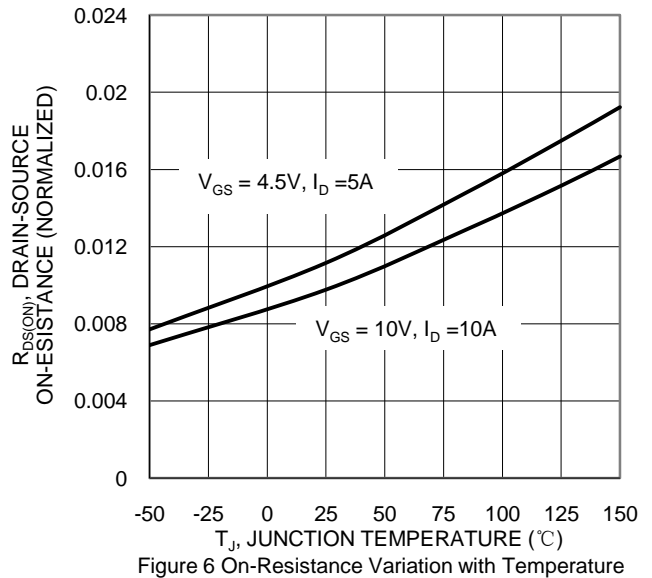
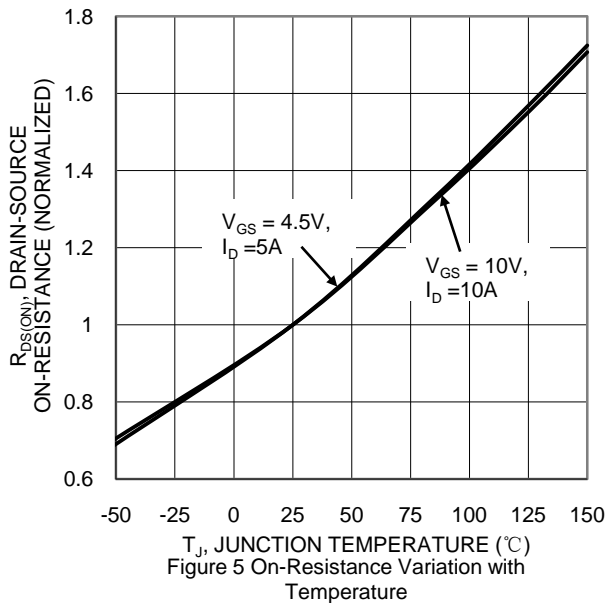
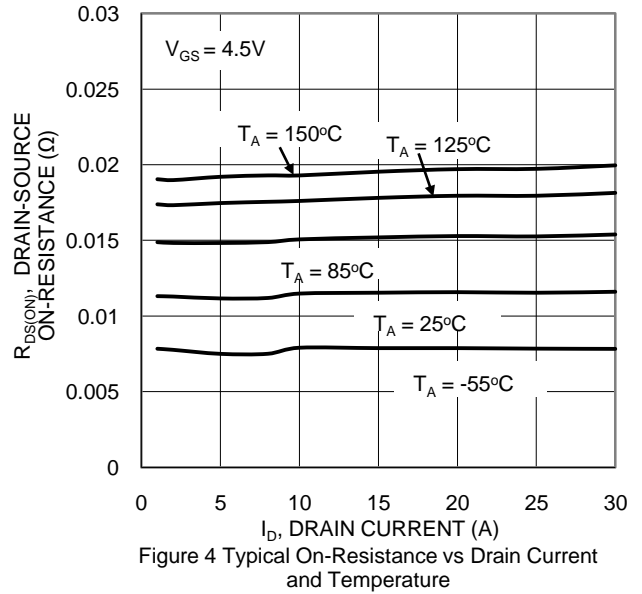
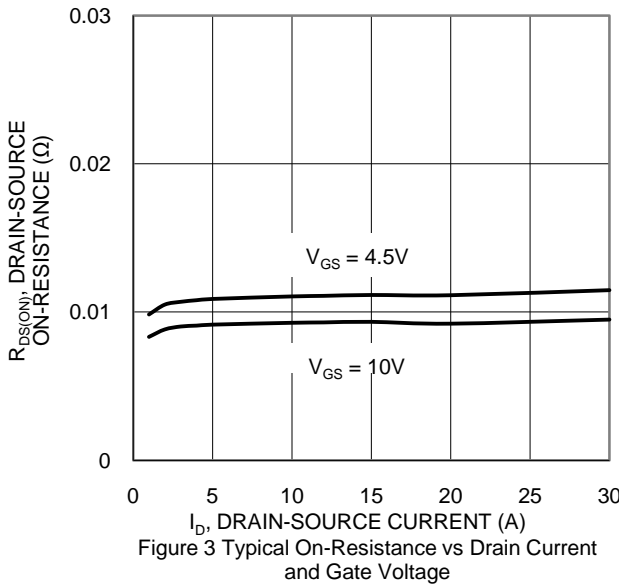
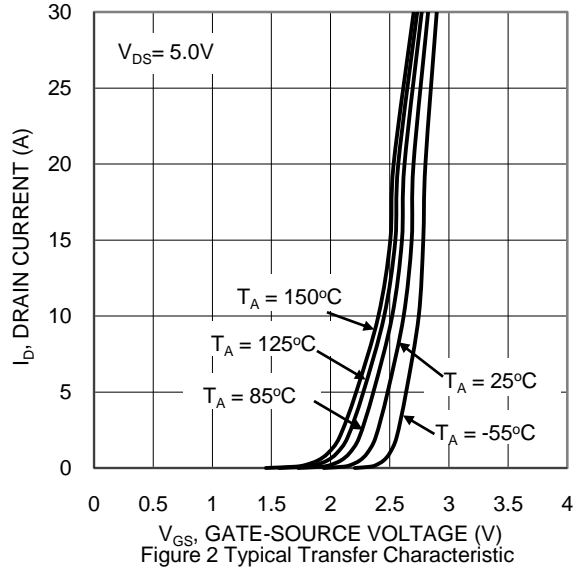
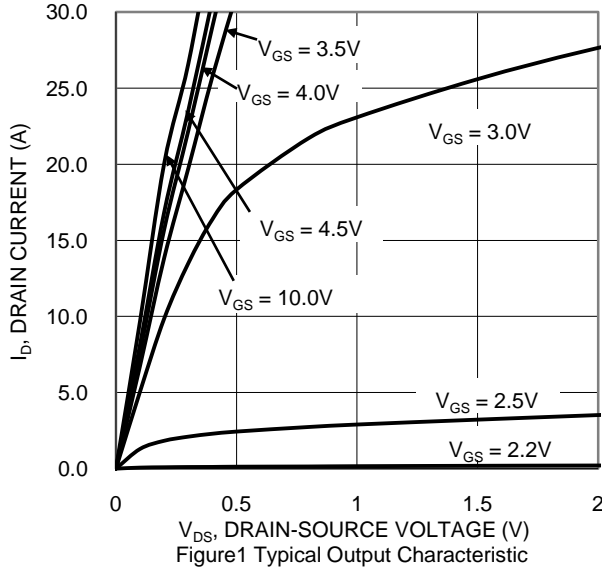
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------------|-----|------|------|------|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 30 | - | - | V | V _{GS} = 0V, I _D = 250μA |
| Zero Gate Voltage Drain Current | I _{DSS} | - | - | 1 | μA | V _{DS} = 30V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | ±100 | nA | V _{GS} = ±20V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.4 | - | 2.0 | V | V _{DS} = V _{GS} , I _D = 250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | - | - | 20 | mΩ | V _{GS} = 10V, I _D = 11A |
| | | - | - | 24 | | V _{GS} = 4.5V, I _D = 9A |
| Diode Forward Voltage | V _{SD} | - | 0.70 | 1.0 | V | V _{GS} = 0V, I _S = 1A |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | C _{iss} | - | 1415 | - | pF | V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 119 | - | | |
| Reverse Transfer Capacitance | C _{rss} | - | 82 | - | | |
| Gate Resistance | R _g | - | 2.6 | - | Ω | V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz |
| Total Gate Charge (V _{GS} = 4.5V) | Q _g | - | 11.3 | - | nC | V _{DS} = 15V, I _D = 12A |
| Total Gate Charge (V _{GS} = 10V) | Q _g | - | 25.1 | - | | |
| Gate-Source Charge | Q _{gs} | - | 3.5 | - | | |
| Gate-Drain Charge | Q _{gd} | - | 3.6 | - | | |
| Turn-On Delay Time | t _{D(ON)} | - | 4.8 | - | ns | V _{DD} = 15V, V _{GS} = 10V, R _L = 1.25Ω, R _G = 3Ω |
| Turn-On Rise Time | t _R | - | 16.5 | - | | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 26.1 | - | | |
| Turn-Off Fall Time | t _F | - | 5.6 | - | | |
| Reverse Recovery Time | t _{RR} | - | 12.3 | - | ns | I _F = 12A, di/dt = 500A/μs |
| Reverse Recovery Charge | Q _{rr} | - | 10.4 | - | nC | |

- Notes:
- Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
 - Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1in. square copper plate.
 - I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to product testing.



DMN3016LDN

NEW PRODUCT





DMN3016LDN

NEW PRODUCT

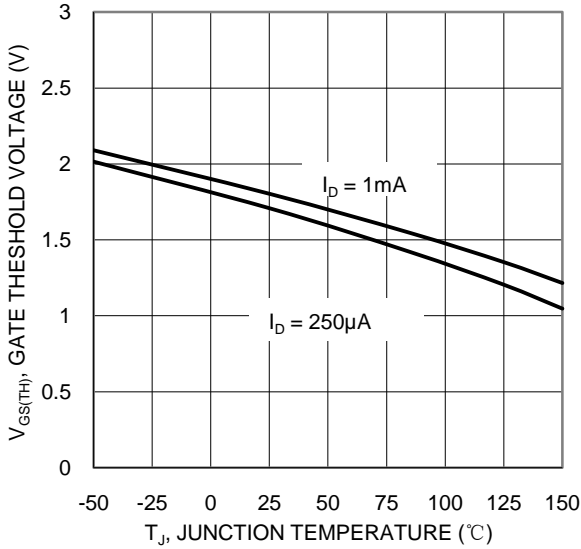


Figure 7 Gate Threshold Variation vs Junction Temperature

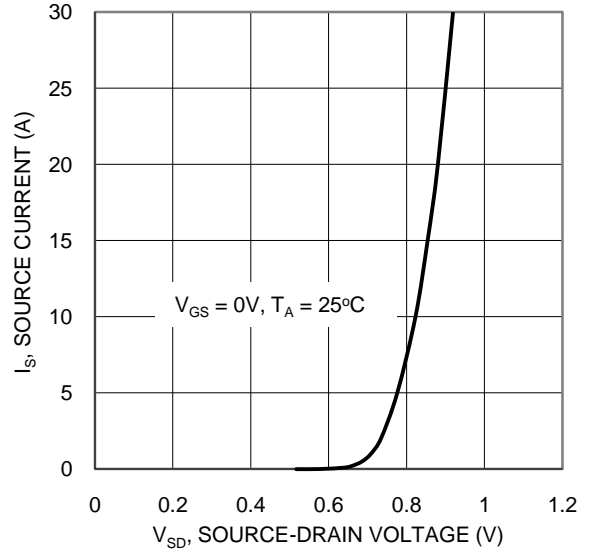


Figure 8 Diode Forward Voltage vs Current

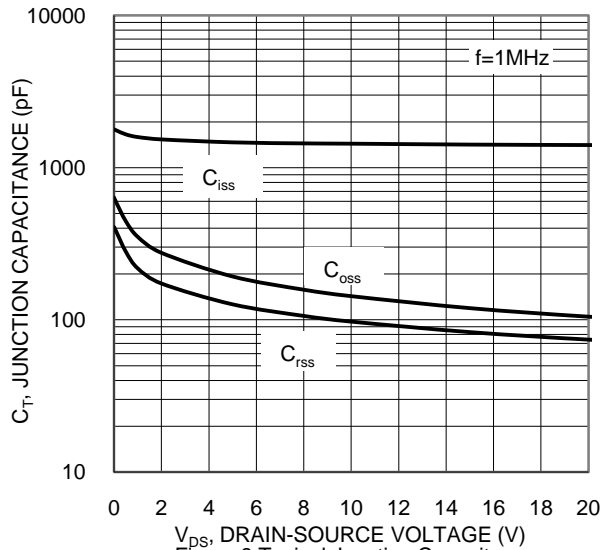


Figure 9 Typical Junction Capacitance

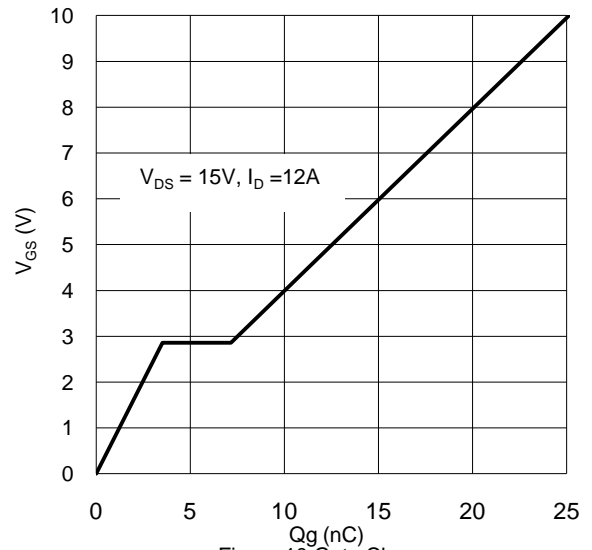


Figure 10 Gate Charge

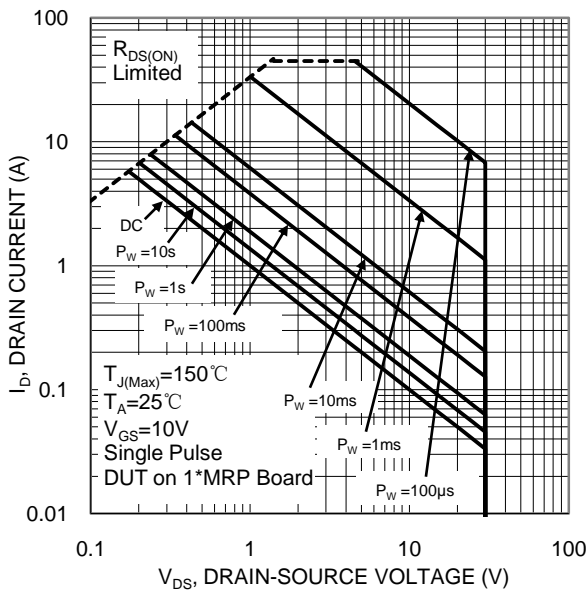


Figure 11 SOA, Safe Operation Area



DMN3016LDN

NEW PRODUCT

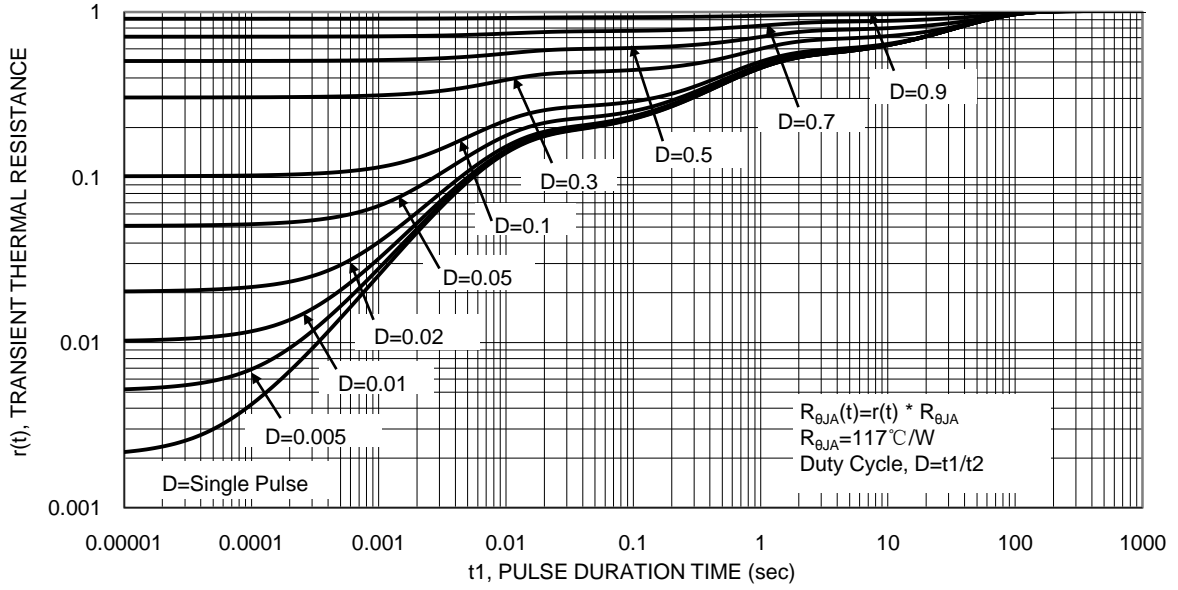


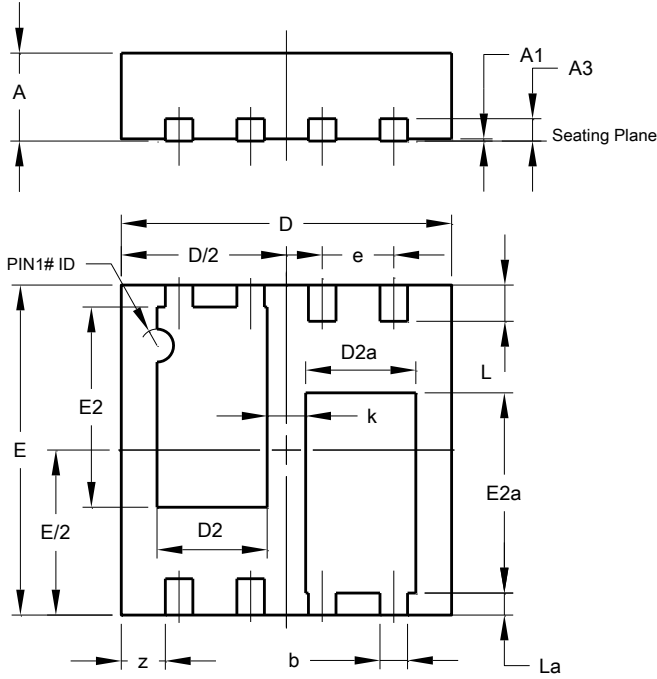
Figure 12 Transient Thermal Resistance



DMN3016LDN

Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

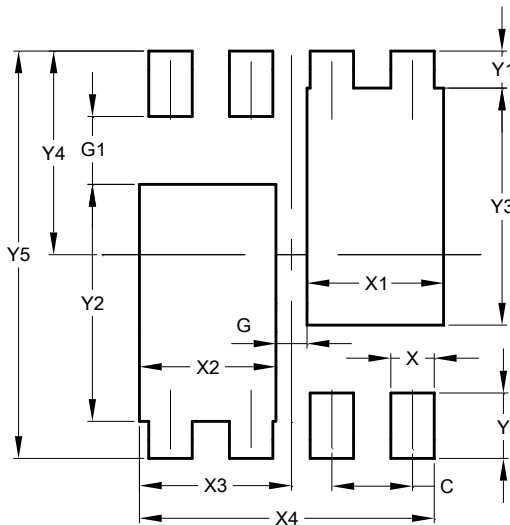


| V-DFN3030-8 (Type J) | | | |
|-------------------------|-----------|-------|------|
| Dim | Min | Max | Typ |
| A | 0.77 | 0.83 | 0.80 |
| A1 | 0.00 | 0.05 | 0.02 |
| A3 | 0.203 BSC | | |
| b | 0.20 | 0.30 | 0.25 |
| D | 2.95 | 3.050 | 3.00 |
| D2 | 0.90 | 1.10 | 1.00 |
| D2a | 0.90 | 1.10 | 1.00 |
| E | 2.95 | 3.050 | 3.00 |
| E2 | 1.72 | 1.92 | 1.82 |
| E2a | 1.72 | 1.92 | 1.82 |
| e | 0.65BSC | | |
| L | 0.27 | 0.38 | 0.33 |
| La | 0.15 | 0.25 | 0.20 |
| k | 0.35 TYP | | |
| z | 0.40 BSC | | |
| All Dimensions in mm | | | |

NEW PRODUCT

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.650 |
| G | 0.250 |
| G1 | 0.550 |
| X | 0.350 |
| X1 | 1.100 |
| X2 | 1.100 |
| X3 | 1.225 |
| X4 | 2.375 |
| Y | 0.530 |
| Y1 | 0.300 |
| Y2 | 1.920 |
| Y3 | 1.920 |
| Y4 | 1.650 |
| Y5 | 3.300 |



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2015, Diodes Incorporated

www.diodes.com

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we stricly control the quality of products and services. Welcome your RFQ to

Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.